2 Watt, High Linearity InGaP HBT Amplifier

**Product Information** 



#### **Product Features**

- 400 2300 MHz
- +33 dBm P1dB
- +51 dBm Output IP3
- 18 dB Gain @ 900 MHz
- 11 dB Gain @ 1960 MHz
- Single Positive Supply (+5V)
- Lead-free/green/RoHS-compliant SOIC-8 SMT Pkg.

#### **Applications**

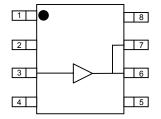
- Final stage amplifiers for Repeaters
- Mobile Infrastructure
- Defense / Homeland Security

#### **Product Description**

The AH312 / ECP200 is a high dynamic range driver amplifier in a low-cost surface mount package. The InGaP/GaAs HBT is able to achieve high performance for various narrowband-tuned application circuits with up to +49 dBm OIP3 and +33 dBm of compressed 1dB power. It is housed in a lead-free/green/RoHS-compliant SOIC-8 package. All devices are 100% RF and DC tested.

The AH312 / ECP200 is targeted for use as a driver amplifier in wireless infrastructure where high linearity and medium power is required. An internal active bias allows the AH312 to maintain high linearity over temperature and operate directly off a single +5V supply. This combination makes the device an excellent candidate for transceiver line cards in current and next generation multi-carrier 3G base stations.

#### **Functional Diagram**



Function	Pin No.
Vref	1
Input	3
Output	6, 7
Vbias	8
GND	Backside Paddle
N/C or GND	2, 4, 5

### Specifications (1)

Parameter	Units	Min	Тур	Max
Operational Bandwidth	MHz	400		2300
Test Frequency	MHz		2140	
Gain	dB	9	10	
Input R.L.	dB		20	
Output R.L.	dB		6.8	
Output P1dB	dBm	+32	+33.2	
Output IP3 (2)	dBm	+47	+48	
IS-95A Channel Power @ -45 dBc ACPR, 1960 MHz	dBm		+27.5	
W-CDMA Channel Power @ -45 dBc ACLR, 2140 MHz	dBm		+25.3	
Noise Figure	dB		7.7	
Operating Current Range, Icc (3)	mA	700	800	900
Device Voltage, Vcc	V		+5	

- 1. Test conditions unless otherwise noted: 25°C, +5V Vsupply, 2140 MHz, in tuned application circuit.
- 3OIP measured with two tones at an output power of +17 dBm/tone separated by 1 MHz. The suppression on the largest IM3 product is used to calculate the 3OIP using a 2:1 rule.
- 3. This corresponds to the quiescent current or operating current under small-signal conditions into pins 6, 7, and 8. It is expected that the current can increase by an additional 200 mA at PIdB. Pin 1 is used as a reference voltage for the internal biasing circuitry. It is expected that Pin 1 will pull 22mA of current when used with a series bias resistor of R1=15Ω. (ie. total device current typically will be 822 mA.)

#### Typical Performance (4)

Parameter	Units		Typical		
Frequency	MHz	900	1960	2140	
S21 – Gain	dB	18	11	10	
S11 – Input R.L.	dB	-18	-19	-20	
S22 – Output R.L.	dB	-11	-6.8	-6.8	
Output P1dB	dBm	+33	+33.4	+33.2	
Output IP3	dBm	+49	+51	+48	
IS-95A Channel Power @ -45 dBc ACPR	dBm	+27	+27.5		
W-CDMA Channel Power @ -45 dBc ACLR	dBm			+25.3	
Noise Figure	dB	8.0	7.3	7.7	
Device Bias (3)		+5 V @ 800 mA			

<sup>4.</sup> Typical parameters reflect performance in a tuned application circuit at  $+25^{\circ}$  C.

#### **Absolute Maximum Rating**

Parameter	Rating
Operating Case Temperature	-40 to +85 °C
Storage Temperature	-65 to +150 °C
RF Input Power (continuous)	+28 dBm
Device Voltage	+8 V
Device Current	1400 mA
Device Power	8 W
Junction Temperature	+250 °C

Operation of this device above any of these parameters may cause permanent damage.

#### **Ordering Information**

Part No.	Description
AH312-S8*	2 Watt, High Linearity InGaP HBT Amplifier (lead-tin SOIC-8 Pkg)
ECP200G*	2 Watt, High Linearity InGaP HBT Amplifier (lead-tin SOIC-8 Pkg)
AH312-S8G	2 Watt, High Linearity InGaP HBT Amplifier (lead-free/green/RoHS-compliant SOIC-8 Pkg)
AH312-S8PCB900	900 MHz Evaluation Board
AH312-S8PCB1960	1960 MHz Evaluation Board
AH312-S8PCB2140	2140 MHz Evaluation Board

<sup>\*</sup> This package is being phased out in favor of the green package type which is backwards compatible for existing designs. Refer to Product Change Notification WJPCN06MAY05TC1 on the WJ website.
Specifications and information are subject to change without notice.

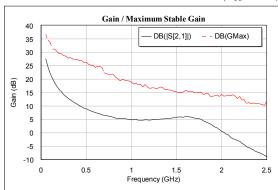
2 Watt, High Linearity InGaP HBT Amplifier

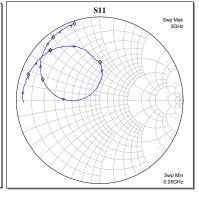
**Product Information** 

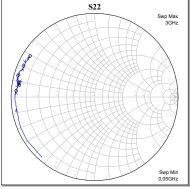


#### **Typical Device Data**

S-Parameters ( $V_{CC} = +5 \text{ V}$ ,  $I_{CC} = 800 \text{ mA}$ ,  $T = 25^{\circ}\text{C}$ , unmatched 50 ohm system)







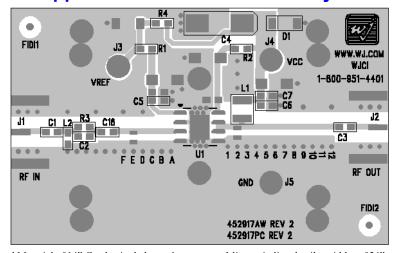
#### Notes:

The gain for the unmatched device in 50 ohm system is shown as the trace in black color. For a tuned circuit for a particular frequency, it is expected that actual gain will be higher, up to the maximum stable gain. The maximum stable gain is shown in the dashed red line. The impedance plots are shown from 50 - 3000 MHz, with markers placed at 0.5 - 3.0 GHz in 0.5 GHz increments.

S-Parameters ( $V_{CC}$  = +5 V,  $I_{CC}$  = 800 mA, T = 25°C, unmatched 50 ohm system, calibrated to device leads)

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Freq (MHz)	S11 (dB)	S11 (ang)	S21 (dB)	S21 (ang)	S12 (dB)	S12 (ang)	S22 (dB)	S22 (ang)
50	-0.86	-178.06	27.55	113.72	-45.75	30.91	-0.38	-130.98
100	-0.64	178.18	22.16	98.81	-45.46	12.80	-0.38	-157.30
200	-0.68	172.85	16.13	89.06	-42.65	6.09	-0.48	-172.51
400	-0.76	164.33	10.61	77.31	-43.96	4.69	-0.48	177.51
600	-0.93	155.56	7.46	67.94	-41.17	6.70	-0.61	173.63
800	-1.15	146.04	5.78	57.62	-41.65	-5.78	-0.66	170.49
1000	-1.50	134.58	4.87	46.90	-40.36	-7.84	-0.71	169.31
1200	-2.39	121.66	4.74	32.96	-40.22	-16.51	-0.80	168.22
1400	-4.47	104.01	5.33	14.01	-38.97	-48.82	-0.76	167.91
1600	-11.96	86.06	5.96	-17.55	-38.96	-86.32	-0.60	170.63
1800	-8.66	-179.11	4.41	-56.78	-39.35	-144.53	-0.52	167.41
2000	-2.76	159.91	0.53	-89.86	-43.55	145.94	-0.41	164.50
2200	-1.21	142.90	-3.21	-107.99	-41.56	104.25	-0.54	160.11
2400	-0.68	130.93	-7.27	-123.14	-42.46	73.64	-0.68	157.84
2600	-0.43	121.91	-10.41	-134.93	-39.71	64.28	-0.73	154.66
2800	-0.32	114.61	-13.28	-143.22	-40.99	58.20	-0.73	151.14
3000	-0.29	108.16	-15.94	-149.93	-39.65	48.40	-0.79	147.52

#### **Application Circuit PC Board Layout**



Circuit Board Material: .014" Getek, single layer, 1 oz copper, Microstrip line details: width = .026", spacing = .026" The silk screen markers 'A', 'B', 'C', etc. and '1', '2', '3', etc. are used as placemarkers for the input and output tuning shunt capacitors – C8 and C9. The markers and vias are spaced in .050" increments.

2 Watt, High Linearity InGaP HBT Amplifier

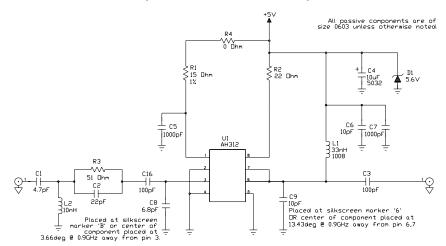
**Product Information** 

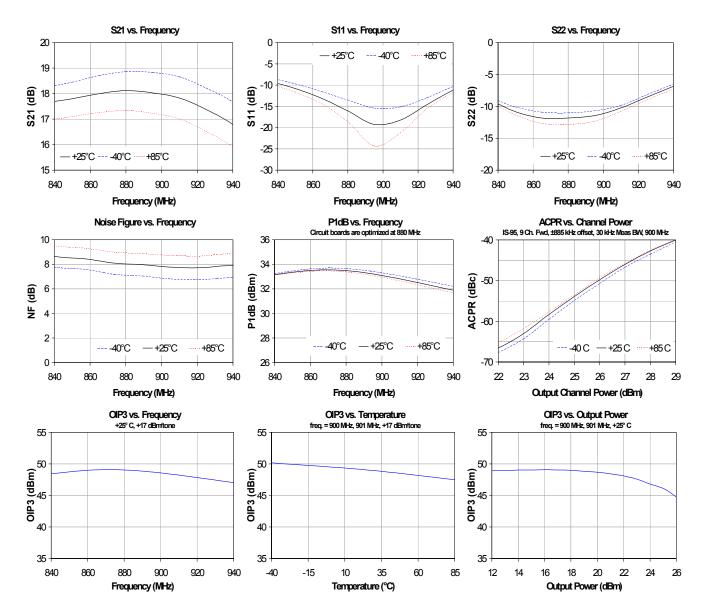


#### 900 MHz Application Circuit (AH312-S8PCB900)

Typical RF Performance at 25°C 900 MHz **Frequency** S21 - Gain 18 dB S11 - Input Return Loss -18 dB S22 - Output Return Loss -11 dB Output P1dB +33 dBm Output IP3 +49 dBm Channel Power +27 dBm (@-45 dBc ACPR, IS-95 9 channels fwd) 8.0 dB Noise Figure Device / Supply Voltage +5 V Quiescent Current (1) 800 mA

This corresponds to the quiescent current or operating current under small-signal conditions into pins 6, 7, and 8.





2 Watt, High Linearity InGaP HBT Amplifier

**Product Information** 

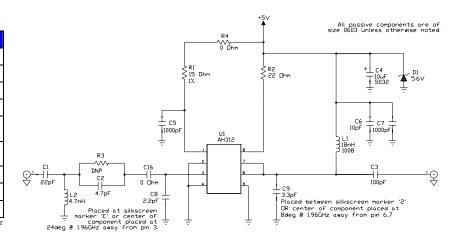


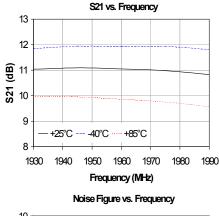
#### 1960 MHz Application Circuit (AH312-S8PCB1960)

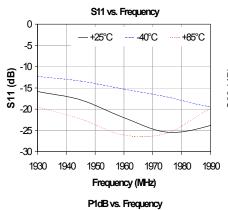
Typical RF Performance at 25°C

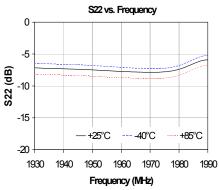
1960 MHz
11 dB
-20 dB
-6.8 dB
+33.4 dBm
+51 dBm
+27.5 dBm
7.3 dB
+5 V
800 mA

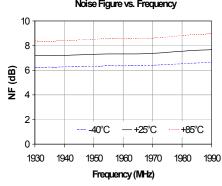
This corresponds to the quiescent current or operating current under small-signal conditions into pins 6, 7, and 8.

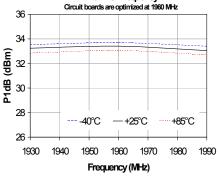




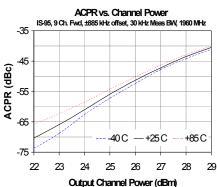


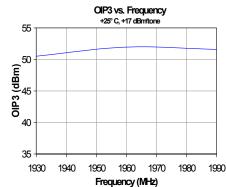


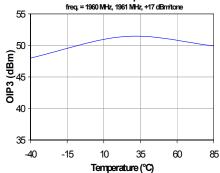




OIP3 vs. Temperature









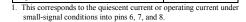
2 Watt, High Linearity InGaP HBT Amplifier

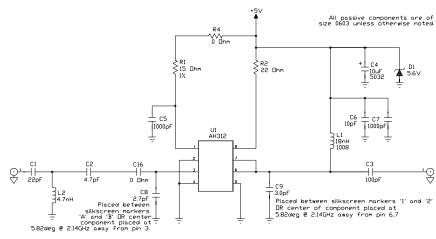
**Product Information** 

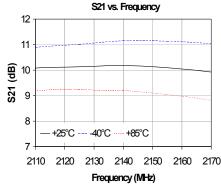


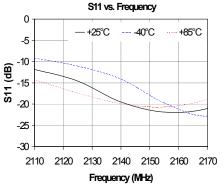
#### 2140 MHz Application Circuit (AH312-S8PCB2140)

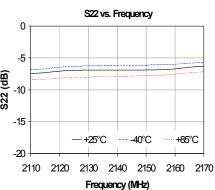
Typical RF Performance at 25°C					
Frequency	2140 MHz				
S21 – Gain	10 dB				
S11 – Input Return Loss	-20 dB				
S22 – Output Return Loss	-6.8 dB				
Output P1dB	+33.2 dBm				
Output IP3 (+17 dBm / tone, 1 MHz spacing)	+48 dBm				
W-CDMA Channel Power (@ -45 dBc ACLR)	+25.3 dBm				
Noise Figure	7.7 dB				
Device / Supply Voltage	+5 V				
Quiescent Current (1)	800 mA				

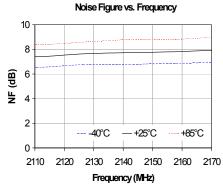


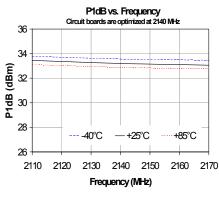


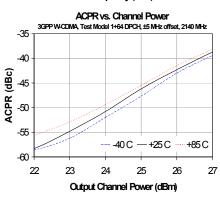


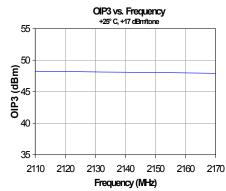


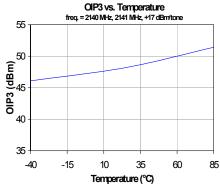


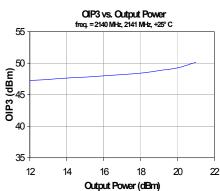












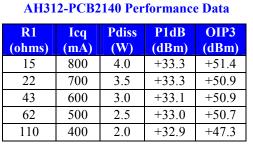
2 Watt, High Linearity InGaP HBT Amplifier

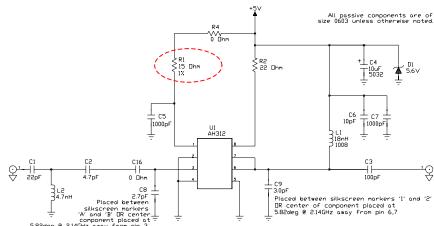
**Product Information** 

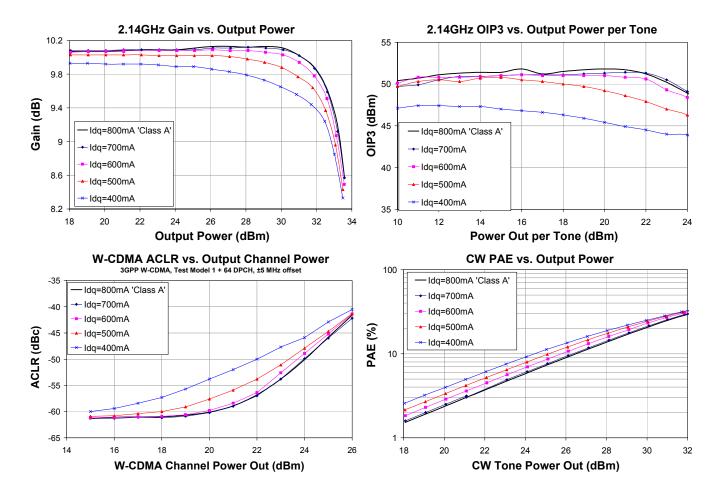


#### **Application Note: Reduced Bias Configurations**

The AH312 / ECP200 can be configured to be operated with lower bias current by varying the bias-adjust resistor – R1. The recommended circuit configurations shown previously in this datasheet have the device operating in Class A operation. Lowering the current has little effect on the gain, OIP3, and P1dB performance of the device, but will slightly lower the ACLR/ACPR performance of the device as shown below. An example of the measured data below represents the AH312 / ECP200 measured and configured for 2.14 GHz applications. It is expected that variation of the bias current for other frequency applications will produce similar performance results.







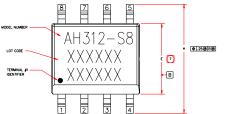
2 Watt, High Linearity InGaP HBT Amplifier

**Product Information** 

#### AH312-S8 (SOIC-8 Package) Mechanical Information

This package may contain lead-bearing materials. The plating material on the leads is SnPl

#### **Outline Drawing**



- NOTES:

  1. EXCEPT WHERE NOTED, THIS PART OUTLINE CONFORMS

  10 JEDEC STANDARD MS-012, ISSUE C FOR SMALL

  OUTLINE (SO) PERPHERAL TERMINALS 3.75mm

  BODY WOTH (PLASTIC).
- DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.4M-1994.
   ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DECREES.
- DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS, WHICH SHALL NOT EXCEED .15mm(.006)
  PER SIDE.
- 6 LENGTH OF TERMINAL FOR SOLDERING TO A SUBSTRA
- DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSIONS WHICH SHALL NOT EXCEED .25mm(.010h) PER SIDE.

## Prod Manying

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### ES Manformation

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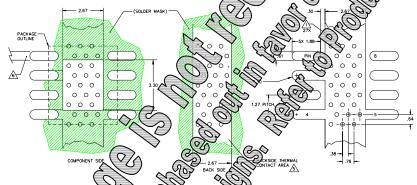
Passes between 500 and 1000V Human Body Model (HBM) JEDEC Standard JESD22-A114

Rating: Level 3 at +235° C convection reflow JEDEC Standard J-STD-020

## **Mounting Config. Notes**

- A heatsink underneath the area of the PCB for the mounted device is strictly required for proper thermal operation. Damage to the device can occur without the use of one.
- Ground / thermal vias are critical for the proper performance of this device. Vias should use a .55mm (#80 / .0135") diameter drill and have a final plated thru diameter of .25 mm (.010").
   Add as much copper as possible to inner and outer layers near the
- Add as much copper as possible to inner and outer layers near th part to ensure optimal thermal performance.
- Mounting screws can be added near the part to fasten the board to a heatsink. Ensure that the ground / thermal via region contacts the heatsink.
- Do not put solder mask on the backside of the PC board in the region where the board contacts the heatsink.
- RF trace width depends upon the PC board material and construction.
- 7. Use 1 oz. Copper minimum.
- 8. All dimensions are in millimeters (inches). Angles are in degrees.

# Land Patt



#### Thermal Societations

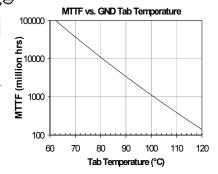
SEATING PLANE

Paramet
Operating
Operating
Operative
Thermal
Operative

1. The the resistance is reference on the hottest part the junc in to cound slug the present the device.

2. Corresponding to the typical biasing condition of the present the typical biasing condition of the present the typical biasing condition of the present the prese

Rth \* Vcc \* Icc



2 Watt, High Linearity InGaP HBT Amplifier

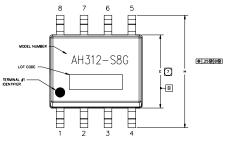
**Product Information** 



#### AH312-S8G (Lead-Free Package) Mechanical Information

This package is lead-free/green/RoHS-compliant. The plating material on the leads is NiPdAu. It is compatible with both lead-free (maximum 260°C reflow temperature) and lead (maximum 245°C reflow temperature) soldering processes.

#### **Outline Drawing**



- NOTES:

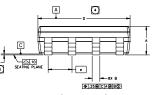
  1. EXCEPT WHERE NOTED, THIS PART OUTLINE CONFORMS

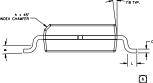
  10 .EDEC STANDARD MS-012, ISSUE C FOR SMALL

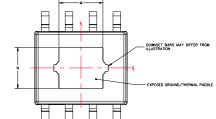
  OUTLINE (SO) PERIPHERAL TERMINALS 3.75mm

  BODY WOTH (PLASTIC).
- DIMENSIONING & TOLERANCING CONFORM TO ANSI Y14,4M-1994.
- ALL DIMENSIONS ARE IN MILLIMETERS (INCHES).
   ANGLES ARE IN DEGREES.

   DOES NOT INCLUDE MOUD ELASH, BROTRIESIONS OR
- DOES NOT INCLUDE WOLD FLASH, PROTRUSIONS OR GATE BURRS, WHICH SHALL NOT EXCEED .15mm(.006in) PER SIDE.
- 5 DEVIATION FROM JEDEC MS-012 STANDARD.
- 6 LENGTH OF TERMINAL FOR SOLDERING TO A SUBSTRATE.
- DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSIONS, WHICH SHALL NOT EXCEED .25mm(,010in) PER SIDE.

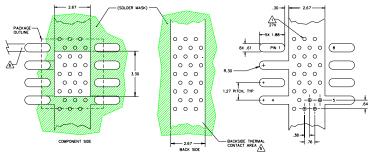






	SYMBOL	м	MILLIMETERS		INCHES		
	STMBUL	MIN	NOM	MAX	MIN	NOM	MAX
(3)	Α	1.42	1.52	1.62	.056	.060	.064
(3)	A1	0	.05	.10	0	.002	.004
3	В	.38	.41	.43	.015	.016	.017
_	С	.19	.20	.25	.007	.008	.010
	D	4.80	4.90	5.00	.189	.193	.197
	Ε	3.80	3.90	4.00	.150	.154	.157
		1.27 BSC			.050 BSC		
	н	5.80	6.0	6.20	.228	.236	.244
	h	.25	.33	.50	.01	.013	.02
(5)	L	.40	.84	1.27	.016	.033	.050
	-	2.21	2.34	2.47	.087	.092	.097
(3)	N	2.08	2.21	2.34	.082	.087	.092
_	α	0	4'8	8'8	0	4'8	8'8

#### **Mounting Configuration / Land Pattern**



#### **Product Marking**

The component will be marked with an "AH312-S8G" designator with an alphanumeric lot code on the top surface of the package.

Tape and reel specifications for this part are located on the website in the "Application Notes" section.

#### **ESD / MSL Information**



Caution! ESD sensitive device.

ESD Rating: Class 1B

Value: Passes between 500 and 1000V Test: Human Body Model (HBM) Standard: JEDEC Standard JESD22-A114

MSL Rating: Level 2 at +260° C convection reflow Standard: JEDEC Standard J-STD-020

#### **Mounting Config. Notes**

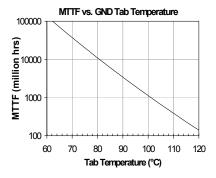
- A heatsink underneath the area of the PCB for the mounted device is strictly required for proper thermal operation. Damage to the device can occur without the use of one.
- Ground / thermal vias are critical for the proper performance of this device. Vias should use a .35mm (#80 / .0135") diameter drill and have a final plated thru diameter of .25 mm (.010").
- Add as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance.
- Mounting screws can be added near the part to fasten the board to a heatsink. Ensure that the ground / thermal via region contacts the heatsink.
- Do not put solder mask on the backside of the PC board in the region where the board contacts the heatsink.
- 6. RF trace width depends upon the PC board material and construction.
- 7. Use 1 oz. Copper minimum.
- 8. All dimensions are in millimeters (inches). Angles are in degrees.

#### **Thermal Specifications**

Parameter	Rating
Operating Case Temperature	-40 to +85° C
Thermal Resistance, Rth (1)	17.5° C / W
Junction Temperature, Tjc (2)	155° C
Noton	

- 1. The thermal resistance is referenced from the hottest part of the junction to the ground slug underneath the device.
- 2. This corresponds to the typical biasing condition of +5V, 800 mA at an 85° C case temperature. A minimum MTTF of 1 million hours is achieved for junction temperatures below 247° C. Tjc is a function of the voltage at pins 6 and 7 and the current applied to pins 6, 7, and 8 and can be calculated by:

Tjc = Tcase + Rth \* Vcc \* Icc



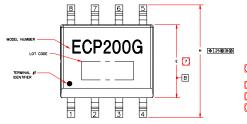
2 Watt, High Linearity InGaP HBT Amplifier

**Product Information** 

#### ECP200G (SOIC-8 Package) Mechanical Information

This package may contain lead-bearing materials. The plating material on the leads is SnP

#### **Outline Drawing**



Ф.25@CA@BS

- NOTES:

  1. EXCEPT WHERE NOTED, THIS PART OUTLINE CONFORMS
  TO JEDEC STANDARD MS-012, ISSUE C FOR SMALL
  OUTLINE (SO) PERIPHERAL TERMINALS 3.75mm
  RDDY WORTH (PLASTIC)
- DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.4M-1994.
- IN DEGREES.

  DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS, WHICH SHALL NOT EXCEED .15mm(.006in)
- 5 DEVIATION FROM JEDEC MS-012 STANDARD.
- 6 LENGTH OF TERMINAL FOR SOLDERING TO A SUBSTRATE.
- DDES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSION
  WHICH SHALL NOT EXCEED .25mm(.010%) PER SIDE.

## Prod Manyig

The composition with an alpha write lot code on the top surface the package.

Tap reel special attions his part are low on the site of "Application sections."

### ES Manformation

Coloni ESD sensitive device.

ESD Rate Class 1B Value Passes be

Passes between 500 and 1000V Human Body Model (HBM) JEDEC Standard JESD22-A114

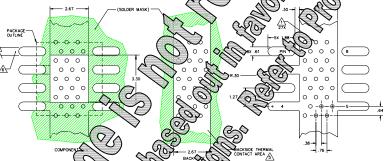
Rating: Level 3 at +235° C convection reflow JEDEC Standard J-STD-020



## **Mounting Config. Notes**

- A heatsink underneath the area of the PCB for the mounted device is strictly required for proper thermal operation. Damage to the device can occur without the use of one.
   Ground / thermal vias are critical for the proper performance of this
- Ground / thermal vias are critical for the proper performance of this device. Vias should use a .35mm (#80 / .0135") diameter drill and have a final plated thru diameter of .25 mm (.010").
- 3. Add as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance.4. Mounting screws can be added near the part to fasten the board to a
- Mounting screws can be added near the part to fasten the board to a heatsink. Ensure that the ground / thermal via region contacts the heatsink.
- 5. Do not put solder mask on the backside of the PC board in the region where the board contacts the heatsink.6. RF trace width depends upon the PC board material and
- RF trace width depends upon the PC board material and construction.
- 7. Use 1 oz. Copper minimum.
- 8. All dimensions are in millimeters (inches). Angles are in degrees.

## Land P



#### Thermal Sporincetions

Operating Competation

Thermal Once, Rth

Junctic Competation

Competa

therm resident is refered from the junction at a property of 85° C. Tjc is a perion of the current of the curre

This sponds typical biasing condition of +5V mA 85° C case temperature. A 1 million hours is achieved for 1 million temperature with the sponds of the spond

# MTTF vs. GND Tab Temperature 100000 (2) 10000 60 70 80 90 100 110 120 Tab Temperature (°C)